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FORM PTO				ATTY DOCKET NO.	SERIAL NO.			
INFORMAT	ION	DISCLOSURE STATE	MENT	536-009.027	To be assigned			
				APPLICANT: Holger RUCKER et al.				
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UNITED STATES PATENT DOCUMENTS								
EXAM. INITIAL		DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
	US	2002/0117733	Aug. 29, 2002	Michael Farjami, Esq.				
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	US	6,642,553	Nov. 4, 2003	Juergen Drews et al.				
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OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)								
	H.J. Osten et al., <i>The Effect of Carbon Incorporation on SiGe Heterobipolar Transistor Performance and Process Margin</i> ; IEEE 1997 0-7803-4100 (pages 32.4.1 - 32.4.4).							
Examiner (To be assigned)				Date:				